查询2SC4634LS供应商

Ordering number : ENN3703B

NPN Triple Diffused Planar Silicon Transistor

2SC4634LS

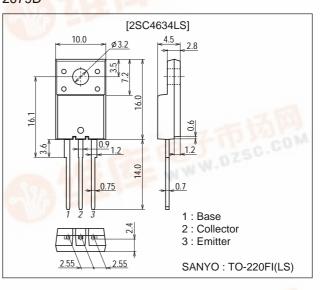
1500V / 10mA High-Voltage Amplifier, High-Voltage Switching Applications

Features

- High breakdown voltage(VCEO min=1500V).
- Small Cob(typical Cob=1.5pF).
- Full-isolation package.
- High reliability(Adoption of HVP process).

Package Dimensions

unit : mm 2079D



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		1500	V
Collector-to-Emitter Voltage	VCEO		1500	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	IC		10	mA
Collector Current (Pulse)	ICP	180 1 4 5 4	30	mA
Collector Dissipation	PC	7.51 9100	2	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg	COM	-55 to +150	°C

Electrical Characteristics at Ta=25°C

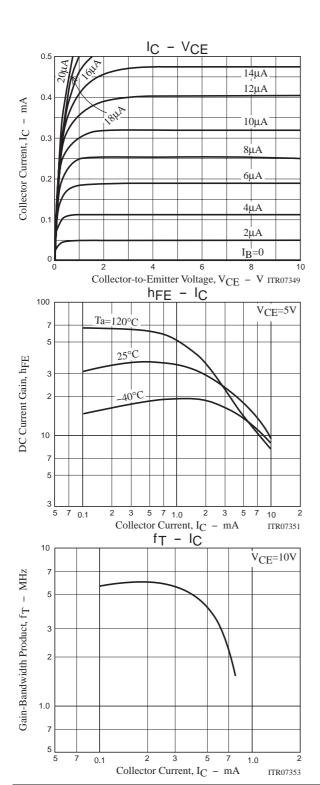
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector Cutoff Current	ICBO	V _{CB} =1500V, I _E =0		-	1	μA
Emitter Cutoff Current	IEBO	VEB=4V, IC=0		art	1	μΑ
DC Current Gain	hFE	V _{CE} =5V, I _C =200μA	10	C	60	
Gain-Bandwidth Product	fŢ	V _{CE} =10V, I _C =200μA	1	6		MHz

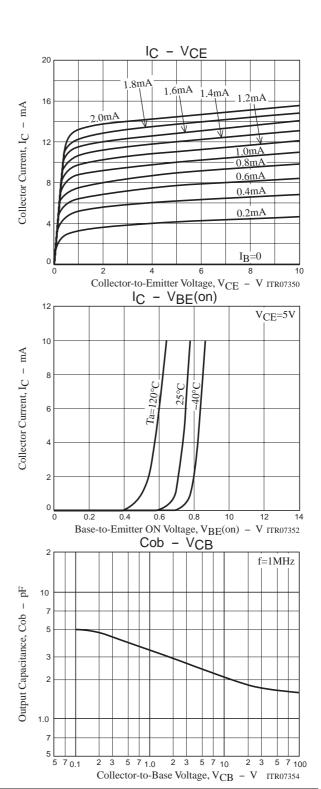
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector-to-Emitter Saturation Voltage	VCE(sat)	IC=500μA, IB=100μA			5	V
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C =500μΑ, I _B =100μΑ			2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=10μA, IE=0	1500			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=100μA, RBE=∞	1500			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=10μA, IC=0	5			V
Output Capacitance	Cob	V _{CB} =100V, f=1MHz		1.5		pF
Thermal Resistance	Rthj-c	Junction – case			12.5	°C / W





VCE(sat) - IC VBE(sat) - IC 5 $I_C / I_B = 5$ З \geq \geq 3 2 I I Saturation Voltage, VCE(sat) Saturation Voltage, VBE(sat) 2 1.0 Collector-to-Emitter Base-to-Emitter Ta= -40°C З 25°C 25°C Ta=120°C 2 120°C 40°C 0 1 5 5 7 1.0 5 7 0.1 2 3 2 3 5 10 2 5 7 0.1 2 3 5 7 1.0 2 3 5 10 Collector Current, IC Collector Current, IC mΑ ITR07355 - mA ITR07356 ASO P_C - Ta 2.4 ICP=30mA ≤50µs 3 2 2.0 ≥ Collector Current, IC - mA I_C=10mA I 10 Collector Dissipation, PC 1.6 5 No heat sint 3 1.2 2 1.0 0.8 7 5 3 0.4 2 Tc=25°C Single pulse 0.1 0 7 100 2 3 5 7 1000 2 20 100 5 0 60 80 120 140 160 40 Collector-to-Emitter Voltage, V_{CE} - V ITR07357 Ambient Temperature, Ta - °C ITR07358

2SC4634LS

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